Panasonic

MSG36C42

SiGe HBT type

For low-noise RF amplifier

Features

- Compatible between high breakdown voltage and high cutoff frequency
- Low-noise, high-gain amplification
- Two elements incorporated into one package (Each transistor is separated)
- SSSMini type package, reduction of the mounting area and assembly cost

Basic Part Number

• MSG330C4 + MSG33002

Absolute Maximum Ratings $T_a = 25^{\circ}C$

	Parameter	Symbol	Rating	Unit
	Collector-base voltage (Emitter open)	V _{CBO}	9	V
Tr1	Collector-emitter voltage (Base open)	V _{CEO}	6	V
	Emitter-base voltage (Collector open)	V _{EBO}	1	V
	Collector current	I _C	100	V mA V V
	Collector-base voltage (Emitter open)	V _{CBO}	9	V
Tr2	Collector-emitter voltage (Base open)	V _{CEO}	6	V
	Emitter-base voltage (Collector open)	V _{EBO}	1	V
	Collector current	I _C	60	V mA
	Total power dissipation *	P _T	125	mW
Overall	Junction temperature	Tj	125	°C
	Storage temperature	T _{stg}	-55 to +125	°C

Package

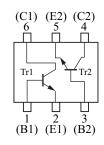
- Code
- SSSMini6-F1
- Pin Name
 - 1: Base (Tr1) 4: Collector (Tr2)
 - 2: Emitter (Tr1)

3: Base (Tr2)

- 5: Emitter (Tr2)
- 6: Collector (Tr1)

Marking Symbol: 6F

Internal Connection



Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

• '	Tr1
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Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base cutoff current (Emitter open)	I _{CBO}	$V_{CB} = 9 V, I_E = 0$			1	μΑ
Collector-emitter cutoff current (Base open)	I _{CEO}	$V_{CE} = 6 V, I_B = 0$			1	μΑ
Emitter-base cutoff current (Collector open)	I _{EBO}	$V_{EB} = 1 V, I_C = 0$			1	μΑ
Forward current transfer ratio	\mathbf{h}_{FE}	$V_{CE} = 3 V, I_C = 15 mA$	100		220	
Transition frequency *	f_T	$V_{CE} = 3 V, I_C = 30 mA, f = 2 GHz$		16		GHz
Forward transfer gain *	$ S_{21e} ^2$	$V_{CE} = 3 V, I_C = 30 mA, f = 2 GHz$	5.0	8.0		dB
Noise figure *	NF	$V_{CE} = 3 V, I_C = 15 mA, f = 2 GHz$		1.6	2.2	dB
Collector output capacitance (Common base, input open circuited) *	C _{ob}	$V_{CB} = 3 V, I_E = 0, f = 1 MHz$		0.7	1.0	pF

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. Observe precautions for handling. Electrostatic sensitive devices.

3. *: Verified by random sampling

• Tr2

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base cutoff current (Emitter open)	I _{CBO}	$V_{CB} = 9 V, I_E = 0$			1	μΑ
Collector-emitter cutoff current (Base open)	I _{CEO}	$V_{CE} = 6 V, I_B = 0$			1	μΑ
Emitter-base cutoff current (Collector open)	I_{EBO}	$V_{EB} = 1 V, I_C = 0$			1	μΑ
Forward current transfer ratio	\mathbf{h}_{FE}	$V_{CE} = 3 V, I_C = 6 mA$	100		220	
Transition frequency *	\mathbf{f}_{T}	$V_{CE} = 3 V, I_C = 20 mA, f = 2 GHz$		19		GHz
Forward transfer gain *	$ S_{21e} ^2$	$V_{CE} = 3 \text{ V}, I_C = 20 \text{ mA}, f = 2 \text{ GHz}$	7.5	10.5		dB
Noise figure *	NF	$V_{CE} = 3 \text{ V}, I_C = 6 \text{ mA}, f = 2 \text{ GHz}$		1.4	2.0	dB
Collector output capacitance (Common base, input open circuited) *	C _{ob}	$V_{CB} = 3 V, I_E = 0, f = 1 MHz$		0.3	0.6	pF

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

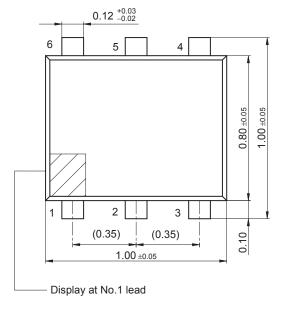
2. Observe precautions for handling. Electrostatic sensitive devices.

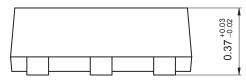
3. *: Verified by random sampling

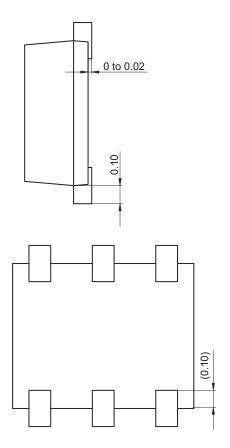
Panasonic

SSSMini6-F1

Unit: mm







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